Single 2-Input OR Gate

The NL17SZ32 is a single 2-input OR Gate in two tiny footprint packages. The device performs much as LCX multi-gate products in speed and drive. They should be used wherever the need for higher speed and drive are needed.

- Tiny SOT-353 and SOT-553 Packages
- 2.4 ns T_{PD} at 5 V (typ)
- Source/Sink 24 mA at 3.0 V
- Over-Voltage Tolerant Inputs
- Pin For Pin with NC7SZ32P5X, TC7SZ32FU and TC7SZ32AFE
- Chip Complexity: FETs = 20
- Designed for 1.65 V to 5.5 V V_{CC} Operation

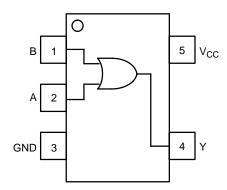


Figure 1. Pinout (Top View)

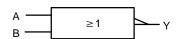


Figure 2. Logic Symbol



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SOT-353/SC70-5/SC-88A DF SUFFIX CASE 419A

MARKING DIAGRAMS



d = Date Code



SOT-553 XV5 SUFFIX CASE 463B



L4 = Device Marking
D = One Digit Date Code

PIN ASSIGNMENT

Pin	Function
1	A
2	В
3	GND
4	Υ
5	V _{CC}

FUNCTION TABLE

Inp	Output Y = A + B	
Α	В	Y
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

MAXIMUM RATINGS

Symbol	Parame	eter	Value	Unit
V _{CC}	DC Supply Voltage		-0.5 to +7.0	V
V _{IN}	DC Input Voltage		-0.5 to +7.0	V
V _{OUT}	DC Output Voltage		-0.5 to $V_{CC} + 0.5$	V
I _{IK}	DC Input Diode Current		-50	mA
I _{OK}	DC Output Diode Current		-50	mA
I _{OUT}	DC Output Sink Current		±50	mA
I _{CC}	DC Supply Current per Supply Pin		±100	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10	Seconds	260	°C
T _J	Junction Temperature Under Bias		+150	°C
θ_{JA}	Thermal Resistance	SOT- 353 (Note 1) SOT- 553	350 496	°C/W
P _D	Power Dissipation in Still Air at 85°C	SOT- 353 SOT- 553	186 135	mW
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
ESD	ESD Classification	Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	Class Z Class A N/A	V

Maximum Ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum-rated conditions is not implied. Functional operation should be restricted to the Recommended Operating Conditions.

- 1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.
- 2. Tested to EIA/JESD22-A114-A, rated to EIA/JESD22-A114-B.
- 3. Tested to EIA/JESD22-A115-A, rated to EIA/JESD22-A115-A.
- 4. Tested to JESD22-C101-A.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit	
V _{CC}	DC Supply Voltage		1.65	5.5	V
V _{IN}	DC Input Voltage		0	5.5	V
V _{OUT}	DC Output Voltage		0	V _{CC} + 0.5	V
T _A	Operating Temperature Range		-40	+85	°C
t _r , t _f	Input Rise and Fall Time $ \begin{array}{c} V_{CC} = 3.0 \ V \ \pm \\ V_{CC} = 5.0 \ V \ \pm \\ \end{array} $	= 0.3 V = 0.5 V	0	100 20	ns/V

DC ELECTRICAL CHARACTERISTICS

			V _{CC}	T _A = 25°C			-40°C ≤	$T_A \leq 85^{\circ}C$	
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Unit
V _{IH}	High-Level Input Voltage		1.65 to 1.95 2.3 to 5.5	0.75 V _{CC} 0.7 V _{CC}			0.75 V _{CC} 0.7 V _{CC}		V
V _{IL}	Low-Level Input Voltage		1.65 to 1.95 2.3 to 5.5			0.25 V _{CC} 0.3 V _{CC}		0.25 V _{CC} 0.3 V _{CC}	V
V _{OH}	High- Level Output Voltage	I _{OH} = 100 μA	1.65 to 5.5	V _{CC} - 0.1	V_{CC}		V _{CC} - 0.1		V
	$V_{IN} = V_{IL} \text{ or } V_{IH}$	$I_{OH} = -3 \text{ mA}$	1.65	1.29	1.52		1.29		
		$I_{OH} = -8 \text{ mA}$	2.3	1.9	2.1		1.9		
		$I_{OH} = -12 \text{ mA}$	2.7	2.2	2.4		2.2		
		$I_{OH} = -16 \text{ mA}$	3.0	2.4	2.7		2.4		
		$I_{OH} = -24 \text{ mA}$	3.0	2.3	2.5		2.3		
		I_{OH} = -32 mA	4.5	3.8	4.0		3.8		
V _{OL}	Low- Level Output Voltage	I _{OL} = 100 μA	1.65 to 5.5			0.1		0.1	V
	$V_{IN} = V_{IH} \text{ or } V_{OH}$	$I_{OL} = 3 \text{ mA}$	1.65		0.08	0.24		0.24	
		$I_{OL} = 8 \text{ mA}$	2.3		0.20	0.3		0.3	
		I_{OL} = 12 mA	2.7		0.22	0.4		0.4	
		$I_{OL} = 16 \text{ mA}$	3.0		0.28	0.4		0.4	
		$I_{OL} = 24 \text{ mA}$	3.0		0.38	0.55		0.55	
		I_{OL} = 32 mA	4.5		0.42	0.55		0.55	
I _{IN}	Input Leakage Current	$V_{IN} = V_{CC}$ or GND	0 to 5.5			± 0.1		±1.0	μΑ
I _{CC}	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	5.5			1		10	μΑ

AC ELECTRICAL CHARACTERISTICS $t_R = t_F = 3.0 \text{ ns}$

			V _{CC}	•	T _A = 25°C		$-40^{\circ}\text{C} \leq \text{T}_{\text{A}} \leq 85^{\circ}\text{C}$		
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Unit
t _{PLH}	Propagation Delay	$R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$	1.65	2.0	5.5	12.0	2.0	12.7	ns
t _{PHL}	(Figure 3 and 4)	$R_L = 1 M\Omega$, $C_L = 15 pF$	1.8	2.0	4.6	10	2.0	10.5	
		$R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$	2.5 ± 0.2	0.8	3.0	7	0.8	7.5	
		$R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$	3.3 ± 0.3	0.5	2.6	4.7	0.5	5.0	
		$R_L = 500 \Omega, C_L = 50 pF$		1.5	3.0	5.2	1.5	5.5	
		$R_L = 1 \text{ M}\Omega$, $C_L = 15 \text{ pF}$	5.0 ± 0.5	0.5	2.2	4.1	0.5	4.4	
		$R_L = 500 \Omega, C_L = 50 pF$		0.8	2.4	4.5	0.8	4.8	

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C _{IN}	Input Capacitance	$V_{CC} = 5.5 \text{ V}, V_I = 0 \text{ V or } V_{CC}$	>4	pF
C _{PD}	Power Dissipation Capacitance	10 MHz, V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC}	25	pF
	(Note 5)	10 MHz, V_{CC} = 5.5 V, V_{I} = 0 V or V_{CC}	30	

^{5.} C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no-load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

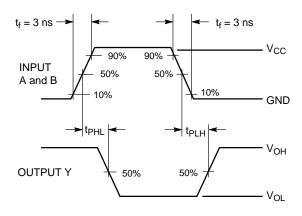
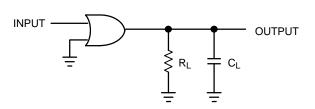


Figure 3. Switching Waveform



A 1 MHz square input wave is recommended for propagation delay tests.

Figure 4. Test Circuit

DEVICE ORDERING INFORMATION

	Device Nomenclature								
Device Order Number	Logic Circuit Indicator	No. of Gates per Package	Temp Range Identifier	Technology	Device Function	Package Suffix	Tape and Reel Suffix	Package Type	Tape and Reel Size
NL17SZ32DFT2	NL	1	7	SZ	32	DF	T2	SC70-5/ SC-88A/ SOT-353	178 mm, 3000 Units
NL17SZ32XV5T2	NL	1	7	SZ	32	XV5	T2	SOT-553	178 mm 4000 units

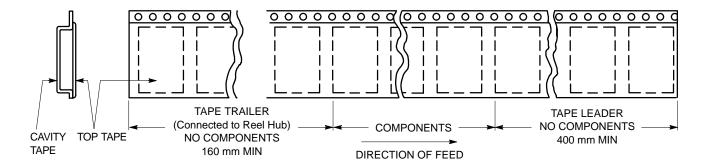
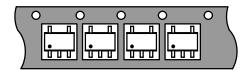
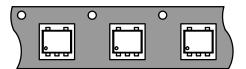


Figure 5. Tape Ends for Finished Goods



"T2" Pin One Opposing Sprocket Hole (3k Reel)

Figure 6. SOT-353/SC70-5/SC-88A Reel Configuration/Orientation



"T2" Pin One Opposing Sprocket Hole (4k Reel)

Figure 7. SOT-553 XV5T2 Reel Configuration/Orientation

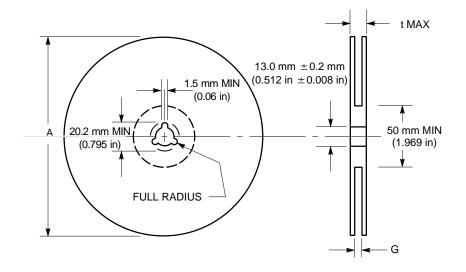


Figure 8. Reel Dimensions

REEL DIMENSIONS†

Tape Size	T and R Suffix	A Max	G	t Max
8 mm	T2	178 mm (7 in)	8.4 mm, + 1.5 mm, -0.0 (0.33 in + 0.059 in, -0.00)	14.4 mm (0.56 in)

†For additional tape and reel information, refer to Brochure BRD8011/D.

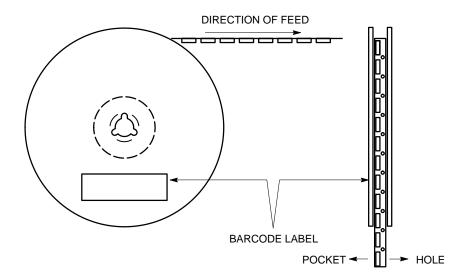
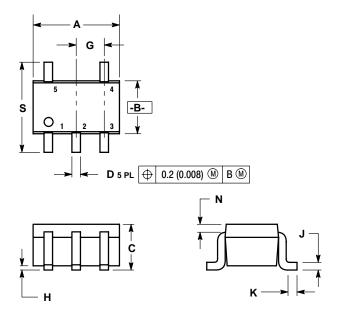


Figure 9. Reel Winding Direction

PACKAGE DIMENSIONS

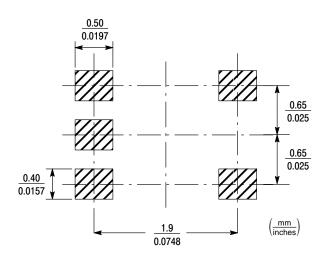
SOT-353 **DF SUFFIX** 5-LEAD PACKAGE

CASE 419A-02 ISSUE F



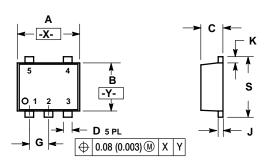
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.071	0.087	1.80	2.20	
В	0.045	0.053	1.15	1.35	
С	0.031	0.043	0.80	1.10	
D	0.004	0.012	0.10	0.30	
G	0.026	BSC	0.65 BSC		
Н		0.004		0.10	
J	0.004	0.010	0.10	0.25	
K	0.004	0.012	0.10	0.30	
N	0.008 REF		0.20	REF	
S	0.079	0.087	2.00	2.20	



PACKAGE DIMENSIONS

SOT-553 XV5 SUFFIX 5-LEAD PACKAGE CASE 463B-01 **ISSUE O**



- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	1.50	1.70	0.059	0.067
В	1.10	1.30	0.043	0.051
С	0.50	0.60	0.020	0.024
D	0.17	0.27	0.007	0.011
G	0.50	BSC	0.020	BSC
J	0.08	0.18	0.003	0.007
K	0.10	0.30	0.004	0.012
S	1.50	1.70	0.059	0.067

STYLE 1: PIN 1 BASE 1 3.

EMITTER 1/2

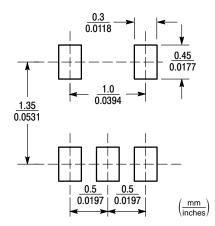
PIN 1. CATHODE BASE 2

STYLE 2:

2. ANODE 3. CATHODE CATHODE

COLLECTOR 2 **COLLECTOR 1**

5. CATHODE



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